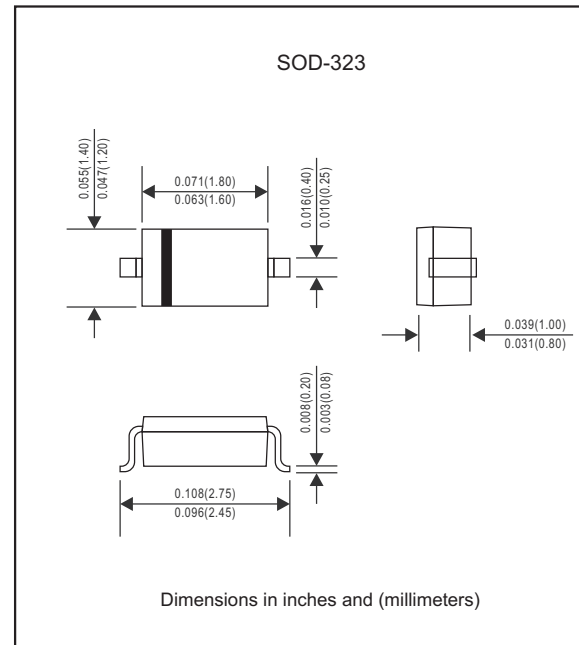


SD103AWS / BWS / CWS**350mA Surface Mount
Small Signal Schottky Diode-20V-40V****Package outline****Features**

- Low current rectification and high speed switching.
- Extremely small surface mount type.
- Low forward voltage drop.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts for green partner, exceeds environmental standards of MIL-STD-19500 /228
- Compliant to Halogen-free

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, SOD-323
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any
- Weight : Approximated 0.004 gram

**Maximum ratings** (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	SD103AWS	SD103BWS	SD103CWS	UNIT
Peak repetitive reverse voltage Working peak reverse voltage DC blocking voltage		V_{RRM} V_{RWM} V_R	40	30	20	V
RMS reverse voltage		$V_{R(RMS)}$	28	21	14	V
Average rectified output current		$I_{F(AV)}$	350			mA
Non-repetitive peak forward surge current	@ $t < 1.0s$	I_{FSM}	1.5			A
Total device dissipation		P_D	200			mW
Thermal resistance	Junction to ambient	$R_{\theta JA}$	625			$^{\circ}\text{C/W}$
Operating temperature		T_J	$-55 \sim +125$			$^{\circ}\text{C}$
Storage temperature		T_{STG}	$-65 \sim +125$			$^{\circ}\text{C}$

Electrical Characteristics(AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	$I_R = 100\mu\text{A}$, SD103AWS $I_R = 100\mu\text{A}$, SD103BWS $I_R = 100\mu\text{A}$, SD103CWS	$V_{(BR)R}$	40 30 20			V
Forward voltage	$I_F = 20\text{mA}$ $I_F = 200\text{mA}$	V_F			0.37 0.60	V
Reverse current	$V_R = 30\text{V}$, SD103AWS $V_R = 20\text{V}$, SD103BWS $V_R = 10\text{V}$, SD103CWS	I_R			5.0	μA
Typical Junction capacitance	$V_R = 0\text{V}$, $f = 1.0\text{MHz}$	C_J		50		pF
Reverse recover time	$I_F = I_R = 200\text{mA}$, $I_{rr} = 0.1 \times I_R$, $R_L = 100_{\text{OHM}}$	t_{rr}		10		ns

Rating and characteristic curves (SD103AWS / BWS / CWS)

Fig. 1 POWER DERATING CURVE

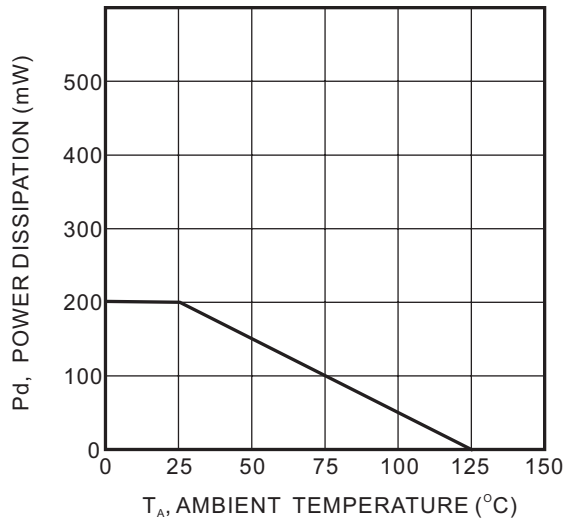


Fig. 2 TYPICAL FORWARD CHARACTERISTIC

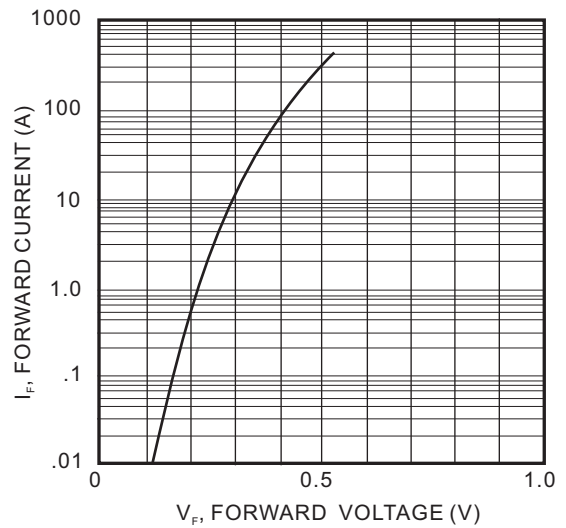
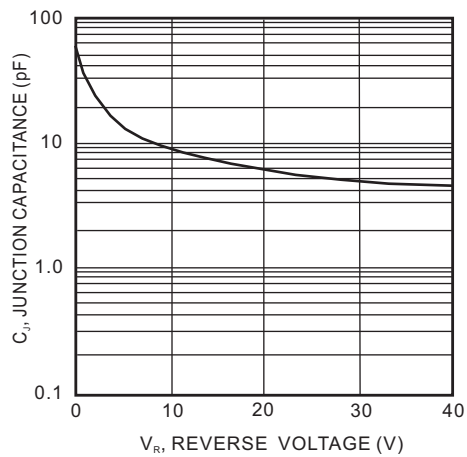


Fig. 3 TYPICAL JUNCTION CAPACITANCE VS REVERSE VOLTAGE

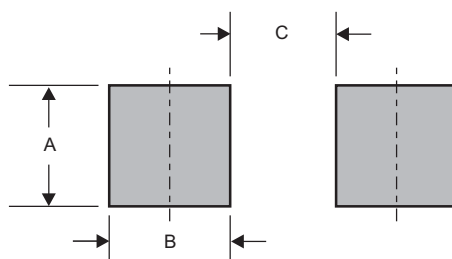


SD103AWS / BWS / CWS**Pinning information**

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

Marking

Type number	Marking code
SD103AWS	S4
SD103BWS	S5
SD103CWS	S6

Suggested solder pad layout

Dimensions in inches and (millimeters)

PACKAGE	A	B	C
SOD-323	0.033 (0.83)	0.025 (0.63)	0.063 (1.60)

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOD-323	7"	3000	4.0	30,000	195*195*150	178	460*400*420	360,000	14.8